







S3D30065A S3D30065H S3D30065G S3D30065D1 650V SIC POWER SCHOTTKY RECTIFIERS

Description

This 650V 30A diode is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D30065A/S3D30065H/S3D30065G/S3D30065D1 are ideal for energy sensitive, high frequency applications in challenging environments.

Features

- 175°C T_J operation
- Ultra-low switching loss
- · Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- · High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

S3D30065A	S3D30065G	S3D30065H	S3D30065D1
1 2 K	K 2	1	1 2 3
TO-220AC	D ² PAK	TO-247AC	TO-247AD
(TO-220-2)	(TO-263-2)	TO-247-2	TO-247-3
PIN 1 O	_−о к	1, K. Cathode 2. Anode	PIN 10———NC PIN 20—————O CASE PIN 30————







Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{DC} \end{array}$	-	650	V
	I _{F (AV)1}	Tc=25°C	84	Α
Average Rectified Forward Current	I _{F (AV)2}	Tc=135°C	37	Α
	I _{F (AV)3}	Tc=146°C	30	Α
D 1311 D 1 D 1 D 1 D 1 D 1 D 1 D 1 D 1 D	I _{FRM1}	10ms, Half Sine pulse, T _C =25°C	125	Α
Repetitive Peak Forward Surge Current	I _{FRM2}	10ms, Half Sine pulse, T _C =110°C	85	Α
Peak One Cycle Non-Repetitive Surge	I _{FSM1}	10ms, Half Sine pulse, T _C =25°C	255	Α
Current	I _{FSM2}	10ms, Half Sine pulse, T _C =110°C	175	Α
Non-Repetitive Peak Forward Surge Current	I _{F,Max1}	10μs. Pulse, T _C =25°C	2165	Α
Guilent	I _{F,Max2}	10μs. Pulse, T _C =110°C	1490	Α
Power Dissipation	P _{tot1} T _C =25°C		246	W
	P _{tot2}	T _C =110°C	107	W

Electrical Characteristics:

Characteristics	Symbol	ymbol Condition		Max.	Units
Forward Voltage Drop*	V _{F1}	@ 30A, Pulse, T _J = 25 °C	1.4	1.7	V
	V _{F2}	@ 30A, Pulse, T _J = 175 °C	1.6	2.0	V
Reverse Current at DC condition*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	4	140	uA
Reverse Current *	I _{R2}	@V _R = rated V _R , T _J = 175 °C	40	400	uA
Junction Capacitance	Ст	V _R =0V, T _J =25℃,f=100MHz	2307	-	pF
Reverse Recovery Charge	Qc	I _F = 30A, di/dt = 200A/μs VR = 400 V, T _J =25°C	143.9	-	nC
Capacitance Stored Energy	Ec	V _R = 400 V, T _J =25°C	35.3	-	μJ

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%



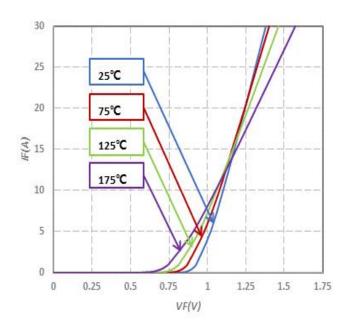




Thermal-Mechanical Specifications:

Characteristics	Symbol	S3D30065A	S3D30065H	S3D30065G	S3D30065D1	Units
Junction Temperature	T_J	-55 to +175			°C	
Storage Temperature	T _{stg}	-55 to +175			°C	
Typical Thermal Resistance Junction to Case	R ₀ JC	1.3	0.61	1.65	0.84(per leg) 0.42(both leg)	°C/W

Ratings and Characteristics Curves



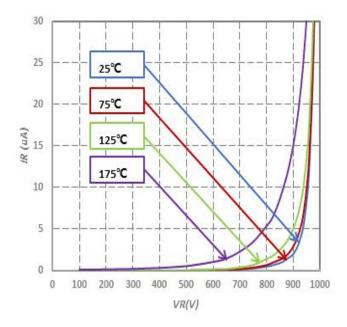


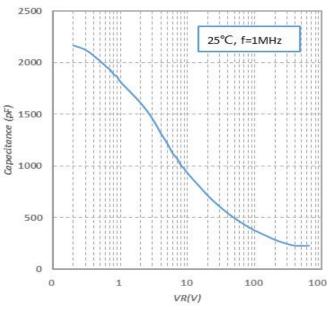
Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics









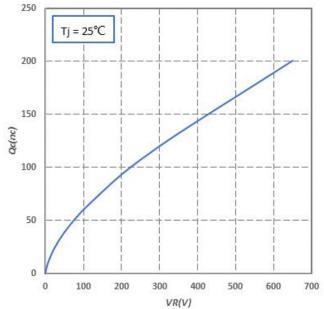
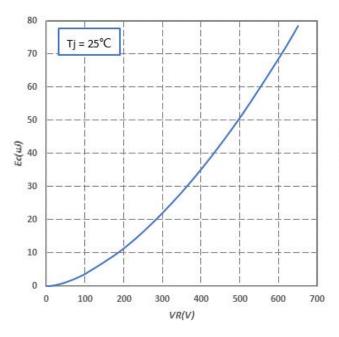


Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Total Capacitance Charge vs. Reverse Voltage



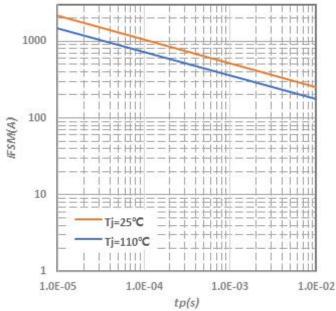


Fig.5-Capacitance Stored Energy

Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

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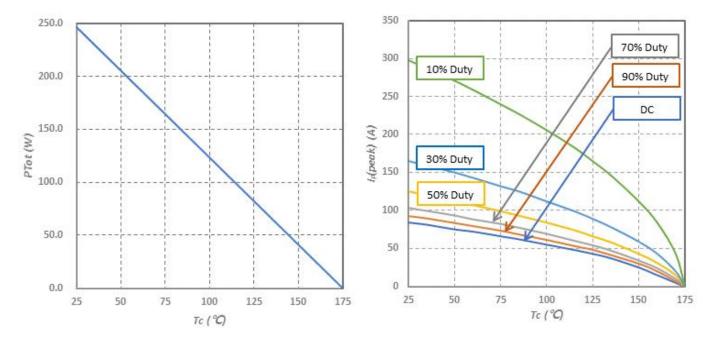
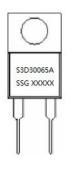


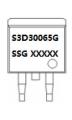
Fig.7-Power Derating

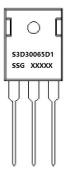
Fig.8-Current Derating

Marking Diagram









Where XXXXX is YYWWL

 S3D
 = Device Type

 30
 = Forward Current (30A)

 065
 = Reverse Voltage (650V)

 A/H/G/D1
 = Package type

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

 Cautions:
 Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
S3D30065A	TO-220AC(TO-220-2)	50pcs / tube
S3D30065H	TO-247AC(TO-247-2)	25pcs / tube
S3D30065G	D ² PAK(TO-263-2)	800pcs / reel
S3D30065GTR	D ² PAK(TO-263-2)	800pcs / reel
S3D30065D1	TO-247AD(TO-247-3)	25pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

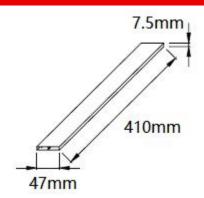
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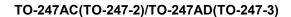


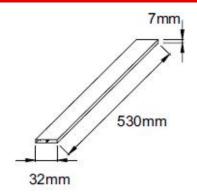




Tube Specification

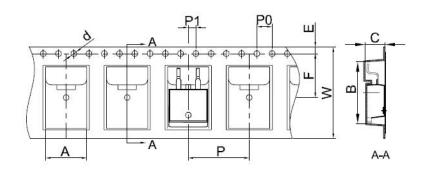






TO-220AC(TO-220-2)

Carrier Tape & Reel Specification D2PAK(TO-263-2)



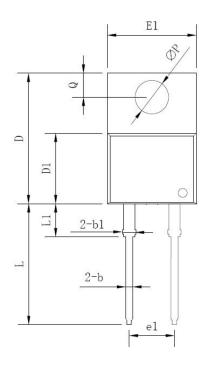
SYMBOL	Millimeters			
STWIDOL	Min.	Max.		
Α	10.70	10.90		
В	16.03	16.23		
С	5.11	5.31		
d	1.45	1.65		
Е	1.65	1.85		
F	11.40	11.60		
P0	3.90	4.10		
Р	15.90	16.10		
P1	1.90	2.10		
W	23.90	24.30		

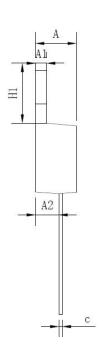






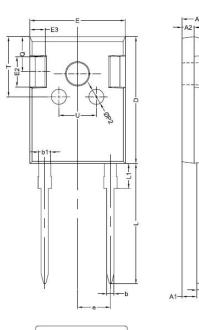
Mechanical Dimensions TO-220AC(TO-220-2)



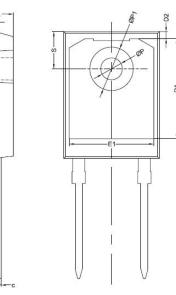


Symbol	Dimensions in millimeters			
,	Min.	Typical	Max.	
Α	3.56	-	4.83	
A1	0.51	-	1.40	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E1	9.65	10.16	10.67	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.70	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

Mechanical Dimensions TO-247AC(TO-247-2)



пп



SYMBOL		Millimeters	;
STIVIBUL	MIN.	TYP.	MAX.
Α	4.80	5.00	5.20
A1	2.20	2.41	2.61
A2	1.90	2.00	2.10
b	1.10	1.20	1.35
b1	1.80	2.00	2.20
С	0.50	0.60	0.75
D	20.30	21.00	21.20
D1		16.58	
D2 E		1.17	
Е	15.60	15.80	16.00
E1		14.02	
E2		5.00	
E3		2.50	
е		5.44	
L	19.42	19.92	20.42
L1		4.13	
Р	3.50	3.60	3.70
P1	7.1	7.19	7.40
P2		2.50	
Q		5.80	
Q S T	6.05	6.15	6.25
Т		10.00	
U		6.20	

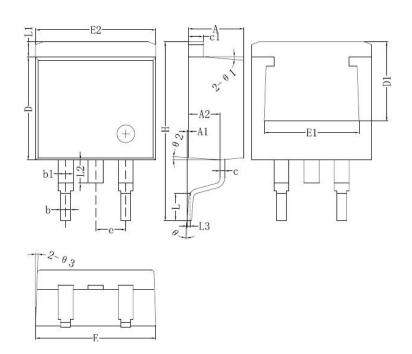
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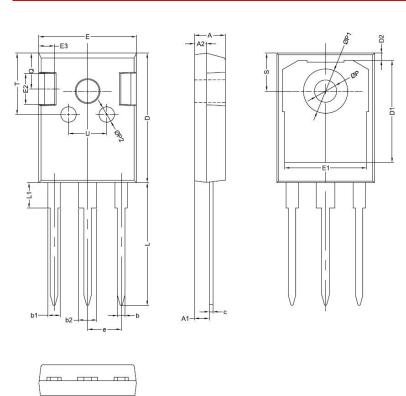


Mechanical Dimensions D²PAK(TO-263-2)



Symbol	Dimensions in millimeters		
	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	8.65	
D1	6.40		
E1	6.22		
E2	9.65	10.67	
е	2.54	BSC	
Н	14.60	15.88	
L	1.78	2.80	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

Mechanical Dimensions TO-247AD(TO-247-3)



SYMBOL	Millimeters				
STIVIBUL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.40		
b1	1.80	2.00	2.20		
b2	2.80	3.00	3.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.55			
D2		1.20			
D2 E	15.45	15.80	16.00		
E1		13.30			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.70		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1		7.40		
P2		2.50			
Q S T		5.80			
S	6.05	6.15	6.25		
T		10.00			
U		6.20			

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S3D30065A S3D30065H S3D30065G S3D30065D1



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